

### **NCE Automotive P-Channel Super Trench Power MOSFET**

### **Description**

The NCEAP40PT15G uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{DS(ON)}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

### **Application**

- Automotive application
- DC/DC Converter
- Ideal for high-frequency switching and synchronous rectification

#### **General Features**

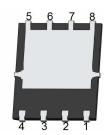
• V<sub>DS</sub> =-40V,I<sub>D</sub> =-160A

 $R_{DS(ON)}$ =2.8m $\Omega$  (typical) @ V<sub>GS</sub>=-10V  $R_{DS(ON)}$ =3.9m $\Omega$  (typical) @ V<sub>GS</sub>=-4.5V

- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance R<sub>DS(on)</sub>
- 175 °C operating temperature
- Pb-free lead plating
- 100% UIS tested
- 100% ΔVds tested
- AEC-Q101 qualified

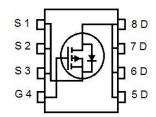
#### **DFN 5X6**





**Top View** 

**Bottom View** 



**Schematic Diagram** 

### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
AP40PT15G	NCEAP40PT15G	DFN5X6-8L	-	-	-

### Absolute Maximum Ratings (T<sub>C</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	-40	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous (Tc=25°C)	I <sub>D</sub> (T <sub>C</sub> =25℃)	-160	А
Drain Current-Continuous(T <sub>C</sub> =100 °C)	I <sub>D</sub> (T <sub>C</sub> =100°C)	-113	А
Pulsed Drain Current	I <sub>DM</sub>	-640	А
Maximum Power Dissipation(T <sub>C</sub> =25 ℃)	P <sub>D</sub>	180	W
Derating factor		1.2	W/°C
Single pulse avalanche energy (Note 1)	Eas	1076	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$

#### **Thermal Characteristic**

Thermal Resistance, Junction-to-Case R <sub>BJC</sub> 0.83 °C/W
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# NCEAP40PT15G

### Electrical Characteristics (T<sub>C</sub>=25 <sup>°</sup>C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =-250μA	-40	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-40V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm20V, V_{DS}=0V$	-	-	±100	nA
On Characteristics			•			
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},I_{D}=-250\mu A$	-0.8	-1.2	-1.8	V
Drain Source On State Decistance	В	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	_	2.8	3.5	mΩ
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-20A	-	3.9	6.0	mΩ
Gate resistance	R <sub>G</sub>	F=1.0MHz	-	5.5	-	Ω
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =-5V,I <sub>D</sub> =-20A	-	30	-	S
Dynamic Characteristics						
Input Capacitance	C <sub>lss</sub>	.,	-	8940	-	PF
Output Capacitance	Coss	$V_{DS}$ =-20V, $V_{GS}$ =0V,	-	1900	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MHz	-	45	-	PF
Switching Characteristics (Note 2)			•			
Turn-on Delay Time	t <sub>d(on)</sub>		-	18	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =-20V, $I_{D}$ =-20A	-	13	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	$V_{GS}$ =-10 $V$ , $R_{G}$ =1.6 $\Omega$	-	90	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg	V 00VI 00A	-	104.4	-	nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ =-20V, $I_{D}$ =-20A,	-	20.8	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =-10V	-	13.5	-	nC
Drain-Source Diode Characteristics			1			
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =-20A	_	-	-1.2	V
Diode Forward Current	Is		-	-	-160	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> =-20A	-	-	35	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	_	-	85	nC

#### Notes:

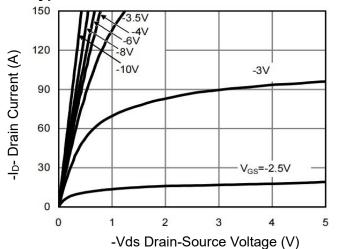
<sup>1.</sup> EAS condition : Tj=25  $^{\circ}\text{C}$  ,VDD=-20V,VG=-10V,L=0.5mH,Rg=25 $\Omega$ 

<sup>2.</sup> Guaranteed by design, not subject to production

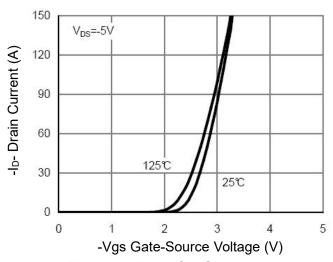
<sup>3.</sup> These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.



### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

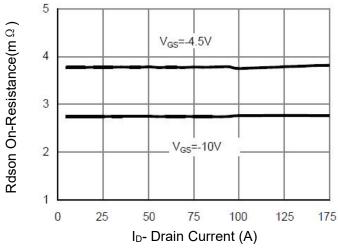


Figure 3 Rdson- Drain Current

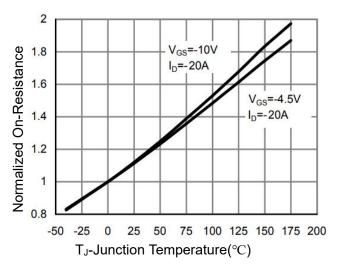


Figure 4 Rdson-JunctionTemperature

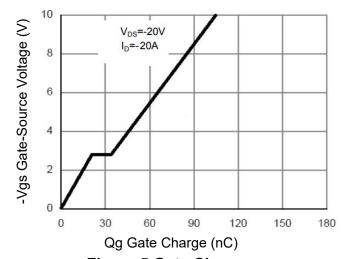


Figure 5 Gate Charge

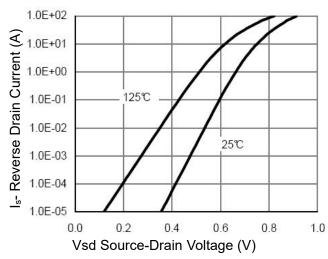


Figure 6 Source- Drain Diode Forward



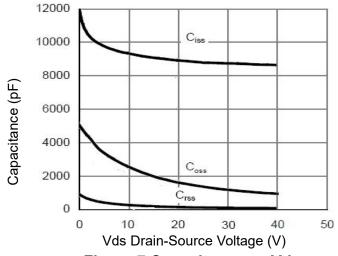


Figure 7 Capacitance vs Vds

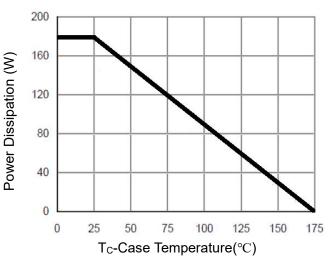


Figure 9 Power De-rating

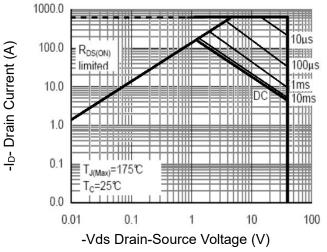


Figure 8 Safe Operation Area (Note3)

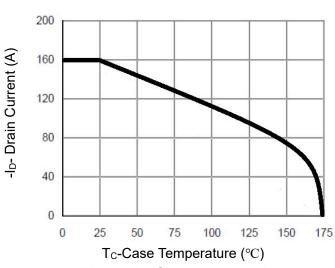


Figure 10 Current De-rating

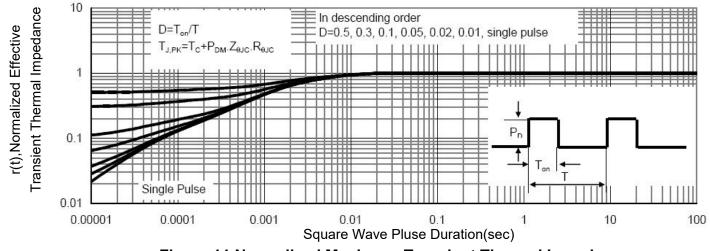
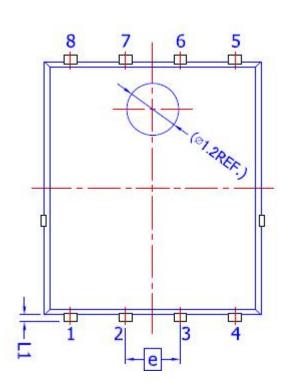
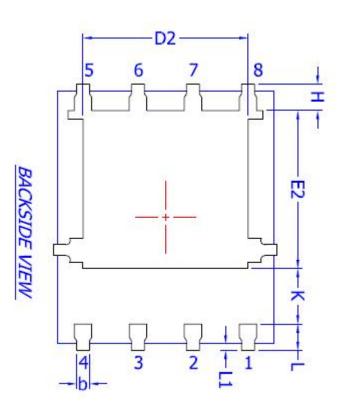


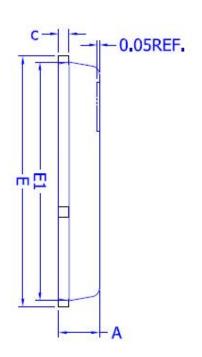
Figure 11 Normalized Maximum Transient Thermal Impedance

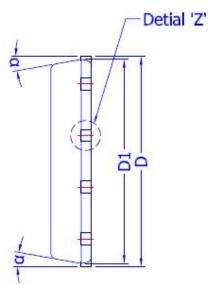


### **DFN5X6-8L Package Information**









DIM	MILLIMETERS			
DIM.	MIN.	NOM.	MAX.	
Α	0.90	1.00	1.10	
A1	0	-	0.05	
Ь	0.30	0.40	0.50	
С	0.20	0.25	0.30	
D	5.15 BSC			
D1	5.00 BSC			
D2	3.76	3.81	3.86	
E	6.15 BSC			
E1	5.80	5.85	5.90	
E2	3.45	3.65	3.85	
е	1.27 BSC			
Н	0.51	0.61	0.71	
K	1.10	3 <del>=</del> 57	3=3	
L	0.51	0.61	0.71	
L1	0.08	0.15	0.23	
α	10°	110	12°	

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# NCEAP40PT15G

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